

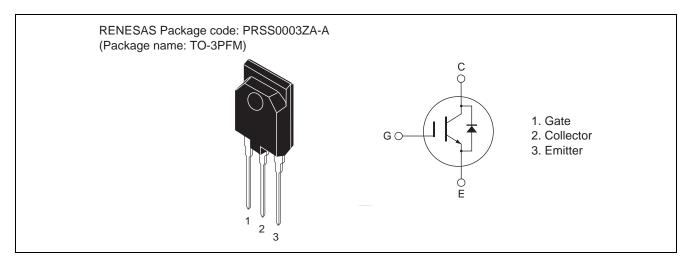
# RJH60D7DPM

600V - 50A - IGBT Application: Inverter R07DS0176EJ0300 Rev.3.00 Apr 19, 2012

### **Features**

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage  $V_{CE(sat)} = 1.6 \text{ V}$  typ. (at  $I_C = 50 \text{ A}, V_{GE} = 15 \text{ V}, Ta = 25^{\circ}\text{C}$ )
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching  $t_f$  = 50 ns typ. (at  $V_{CC}$  = 300 V,  $V_{GE}$  = 15 V,  $I_C$  = 50 A, Rg = 5  $\Omega$ , Ta = 25°C, inductive load)

### **Outline**



# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	600	V
Gate to emitter voltage		$V_{GES}$	±30	V
Collector current	Tc = 25°C	Ic	90	Α
	Tc = 100°C	Ic	50	Α
Collector peak current		ic(peak) Note1	200	Α
Collector to emitter diode forward current		i <sub>DF</sub>	30	Α
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) Note1	120	Α
Collector dissipation		P <sub>C</sub> Note2	55	W
Junction to case thermal resistance (IGBT)		θj-c <sup>Note2</sup>	2.27	°C/W
Junction to case thermal resistance (Diode)		θj-cd <sup>Note2</sup>	3.95	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tc = 25°C

# **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage	V <sub>BR(CES)</sub>	600	_	_	V	$I_C = 10 \mu A, V_{GE} = 0$	
Zero gate voltage collector current / Diode reverse current	I <sub>CES</sub> / I <sub>R</sub>	_	_	5	μА	V <sub>CE</sub> = 600 V, V <sub>GE</sub> = 0	
Gate to emitter leak current	I <sub>GES</sub>	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{\text{GE(off)}}$	4.0	_	6.0	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	1.6	2.2	V	$I_C = 50 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	$V_{CE(sat)}$	_	1.8	_	V	$I_C = 90 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	3000	_	pF	V <sub>CE</sub> = 25 V	
Output capacitance	Coes	_	160	_	pF	$V_{GE} = 0$	
Reveres transfer capacitance	Cres	_	85	_	pF	f = 1 MHz	
Total gate charge	Qg	_	130	_	nC	V <sub>GE</sub> = 15 V V <sub>CE</sub> = 300 V	
Gate to emitter charge	Qge	_	20	_	nC		
Gate to collector charge	Qgc	_	45	_	nC	$I_{C} = 50 \text{ A}$	
Turn-on delay time	t <sub>d(on)</sub>	_	60	_	ns	$V_{CC} = 300 \text{ V}$ $V_{GE} = 15 \text{ V}$ $I_{C} = 50 \text{ A}$ $Rg = 5 \Omega$	
Rise time	t <sub>r</sub>	_	46	_	ns		
Turn-off delay time	t <sub>d(off)</sub>	_	190	_	ns		
Fall time	t <sub>f</sub>	_	50	_	ns		
Turn-on energy	Eon	_	1.1	_	mJ	(Inductive load)	
Turn-off energy	E <sub>off</sub>	_	0.6	_	mJ		
Total switching energy	E <sub>total</sub>	_	1.7	_	mJ		
Short circuit withstand time	t <sub>sc</sub>	3.0	5.0	_	μS	$V_{CC} \leq 360~V,~V_{GE} = 15~V$	
FRD forward voltage	V <sub>F</sub>	_	1.4	1.9	V	$I_F = 30 \text{ A}^{\text{Note3}}$	
FRD reverse recovery time	t <sub>rr</sub>	_	100	_	ns	I <sub>F</sub> = 30 A	
FRD reverse recovery charge	Qrr	_	0.18	_	μС	di <sub>F</sub> /dt = 100 A/μs	

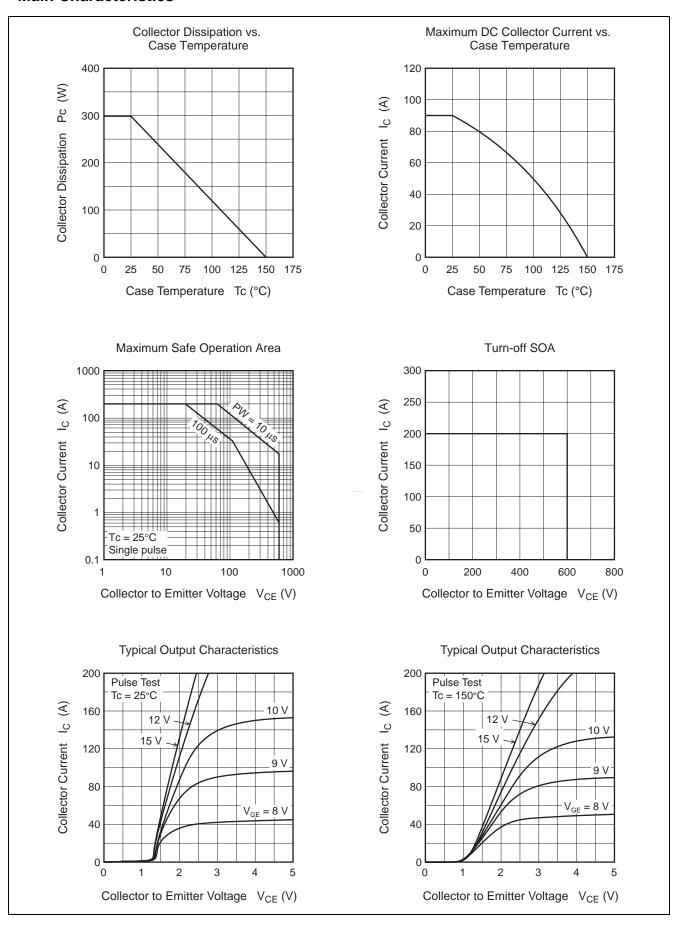
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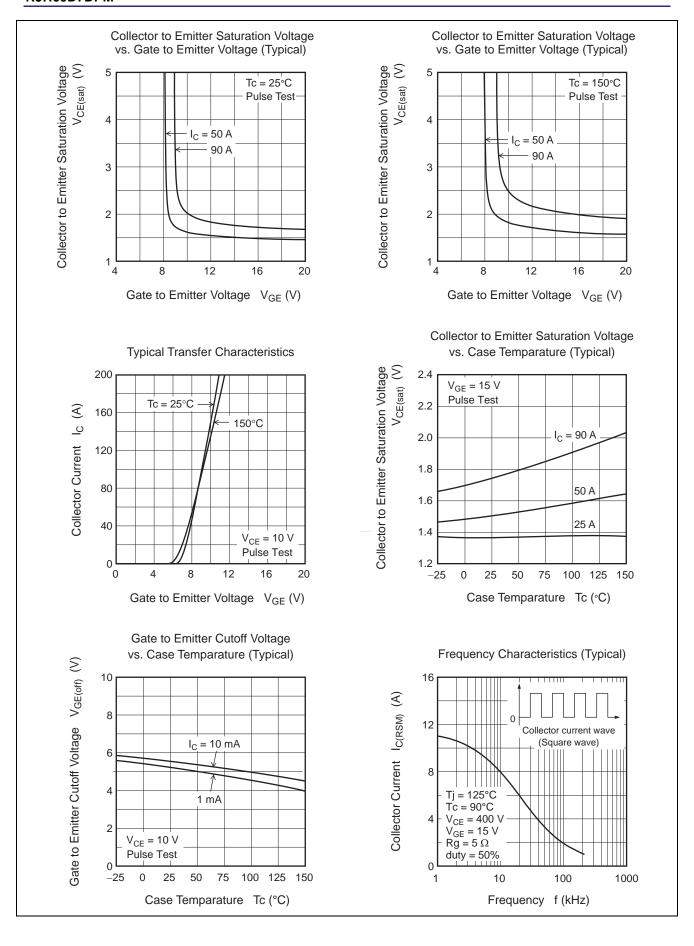
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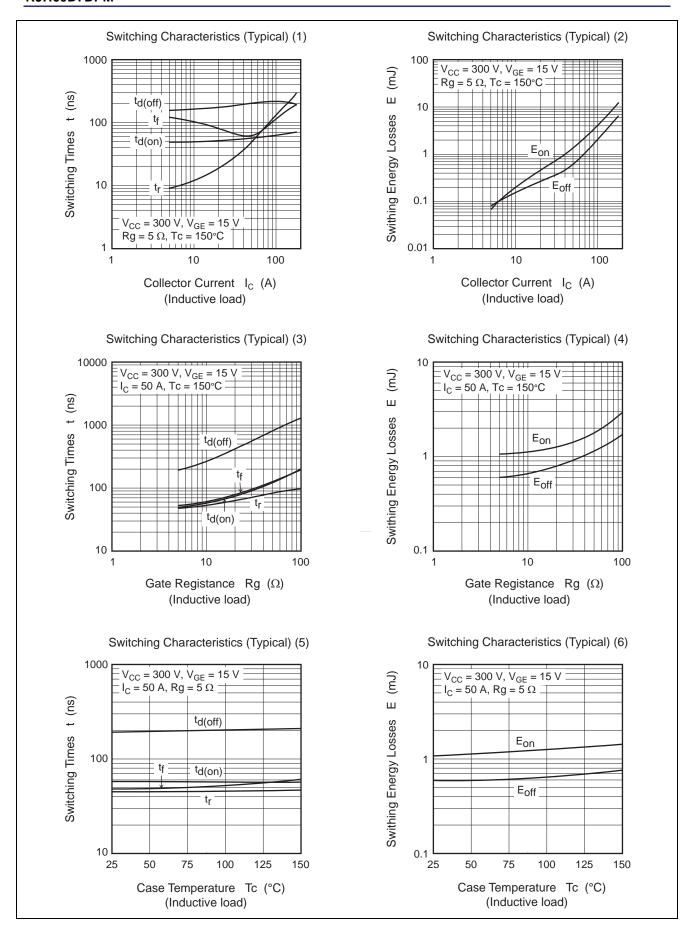
Notes: 3. Pulse test

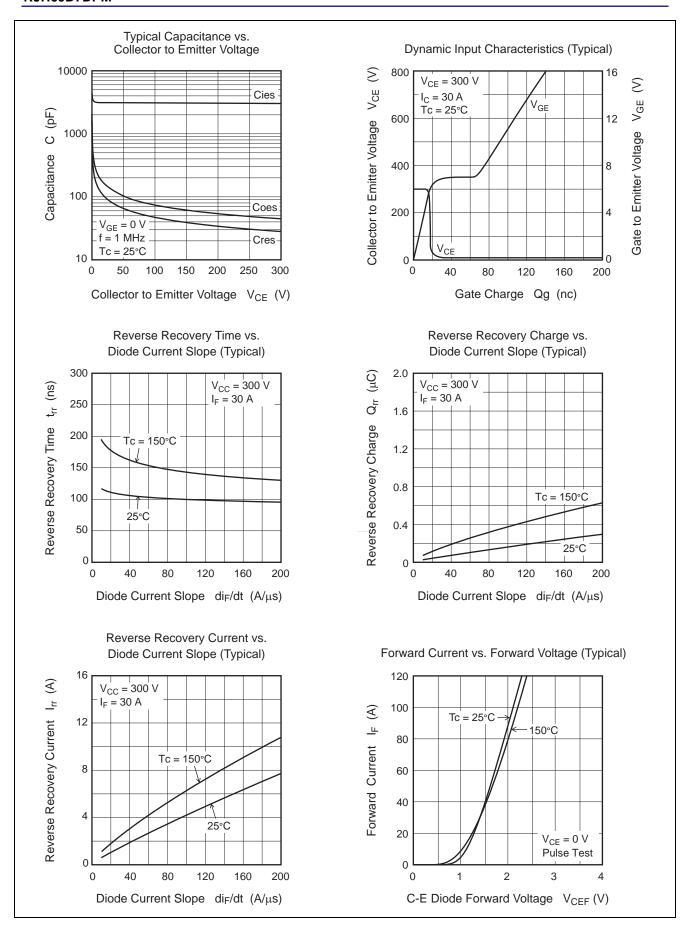
FRD peak reverse recovery current

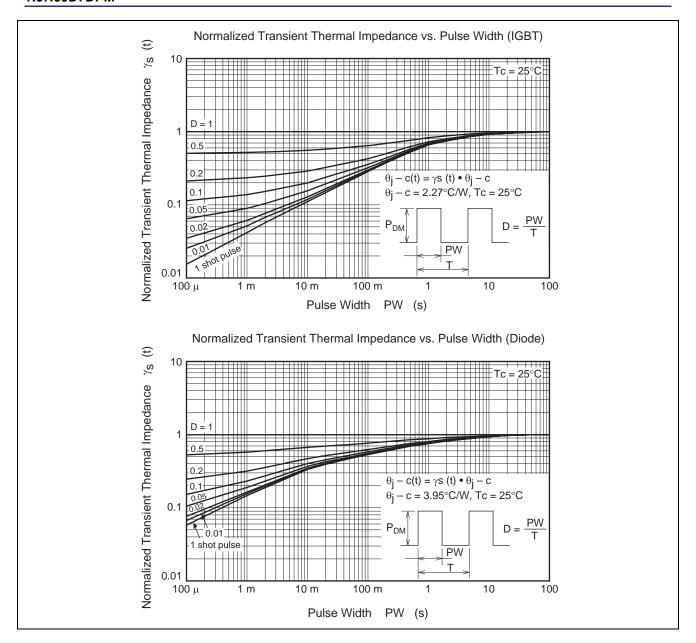
## **Main Characteristics**

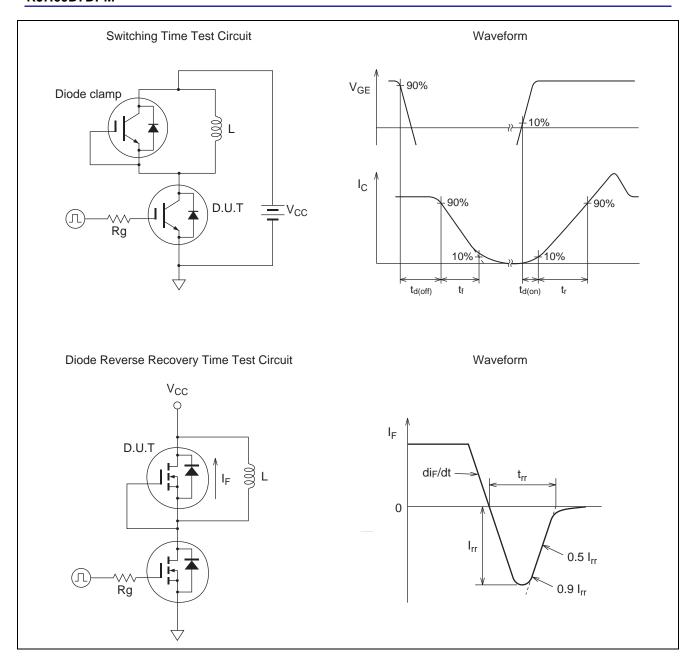




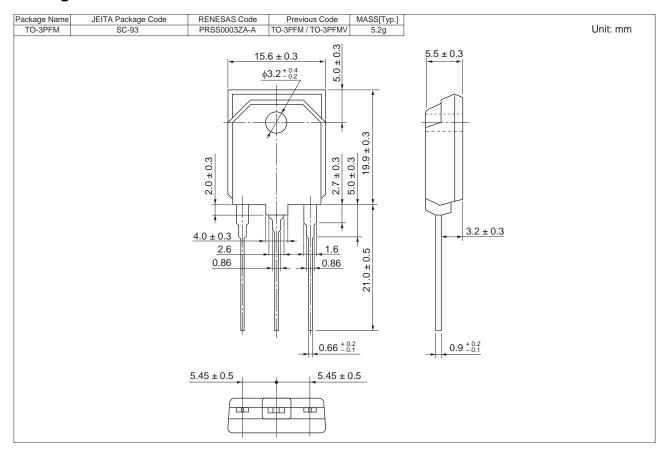








# **Package Dimension**



# **Ordering Information**

Orderable Part No.	Quantity	Shipping Container
RJH60D7DPM-00#T1	360 pcs	Box (Tube)

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